Nch 600V 4A Power MOSFET

V _{DSS}	600V
R _{DS(on)} (Max.)	0.98Ω
I _D	±4.0A
P _D	40W

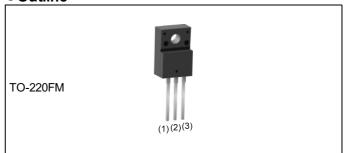
Features

- 1) Low on-resistance
- 2) Ultra fast switching
- 3) Parallel use is easy
- 4) Pb-free plating; RoHS compliant

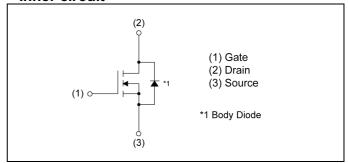
Application

Switching

Outline



•Inner circuit



Packaging specifications

Code	Packing
C7 G	Tube
C7	Tube*
- (Blank)	Bulk*

^{*}Package dimensions are different

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit	
Drain - Source voltage	V_{DSS}	600	V	
Continuous drain current		I _D *1	±4.0	Α
Pulsed drain current		I _{DP} *2	±12	Α
static		V	±20	V
Gate - Source voltage AC(f>1Hz)		V_{GSS}	±30	V
Avalanche current, single pulse		I _{AS}	0.8	Α
Avalanche energy, single pulse		E _{AS} *3	46	mJ
Power dissipation (T _c = 25°C)	P _D	40	W	
Junction temperature	Tj	150	°C	
Operating junction and storage tempera	ature range	T _{stg}	-55 to +150	°C

●Thermal resistance

Downwortow	Cymah al	Values			1.1:4
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R _{thJC} *4	-	-	3.13	°C/W
Thermal resistance, junction - ambient	R _{thJA}	-	-	70	°C/W
Soldering temperature, wavesoldering for 10s	T _{sold}	-	-	265	°C

• Electrical characteristics $(T_a = 25^{\circ}C)$

Darameter	Cumb al	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V$, $I_D = 1mA$	600	-	-	V
		V _{DS} = 600V, V _{GS} = 0V				
Zero gate voltage drain current	I _{DSS}	$T_j = 25^{\circ}C$	-	-	100	μΑ
		$T_j = 125^{\circ}C$	-	-	1000	
Gate - Source leakage current	I _{GSS}	V_{GS} = ±20V, V_{DS} = 0V	1	1	±100	nA
Gate threshold voltage	V _{GS(th)}	V _{DS} = 10V, I _D = 1mA	3	-	5	V
		V _{GS} = 10V, I _D = 1.5A				
Static drain - source on - state resistance	R _{DS(on)} *5	$T_j = 25^{\circ}C$	-	0.90	0.98	Ω
		$T_j = 125^{\circ}C$	-	1.36	-	
Gate resistance	R_{G}	f = 1MHz, open drain	-	3.3	-	Ω

● Electrical characteristics (T_a = 25°C)

Davamatar	Cymah al	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward Transfer Admittance	Y _{fs} *5	V _{DS} = 10V, I _D = 2A	1.5	3.0	-	S
Input capacitance	C _{iss}	V _{GS} = 0V	-	280	-	
Output capacitance	C _{oss}	V _{DS} = 25V	-	280	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	16	-	
Turn - on delay time	t _{d(on)} *5	$V_{DD} \simeq 300V$, $V_{GS} = 10V$	-	15	-	
Rise time	t _r *5	I _D = 2A	-	10	-	20
Turn - off delay time	t _{d(off)} *5	$R_L \simeq 150\Omega$	-	30	-	ns
Fall time	t _f *5	$R_G = 10\Omega$	-	25	-	

● Gate charge characteristics (T_a = 25°C)

Darameter	Complete al	Conditions	Values			l limit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Total gate charge	Q_g^{*5}	V _{DD} ≈ 300V	-	10.2	-	
Gate - Source charge	Q _{gs} *5	I _D = 4A	-	2.5	-	nC
Gate - Drain charge	Q _{gd} *5	V _{GS} = 10V	-	4.8	-	
Gate plateau voltage	V _(plateau)	V _{DD} ≈ 300V, I _D = 4A	-	5.8	-	V

^{*1} Limited only by maximum channel temperature allowed.

^{*2} Pw ≤ 10µs, Duty cycle ≤ 1%

^{*3} L $\stackrel{=}{=}$ 100mH, V_{DD}=50V, R_G=25 Ω , STARTING T_j=25 $^{\circ}$ C

^{*4} T_C=25°C

^{*5} Pulsed

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Doromotor	Cumph of	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Continuous forward current	I _S *1	T - 25°C	1	1	4.0	А
Pulse forward current	I _{SP} *2	T _C = 25°C	-	-	12	А
Forward voltage	V _{SD} *5	V _{GS} = 0V, I _S = 4A	-	-	1.5	V
Reverse recovery time	t _{rr} *5		-	230	-	ns
Reverse recovery charge	Q _{rr} *5	I _S = 4A di/dt = 100A/µs	-	1.5	-	μC
Peak reverse recovery current	I _{rrm} *5	- α,, ατ 100/ γμο	-	12	-	Α

● Typical transient thermal characteristics

Symbol	Value	Unit
R _{th1}	0.557	
R _{th2}	1.61	K/W
R _{th3}	2.24	

Symbol	Value	Unit
C _{th1}	0.00102	
C _{th2}	0.00898	Ws/K
C _{th3}	0.440	

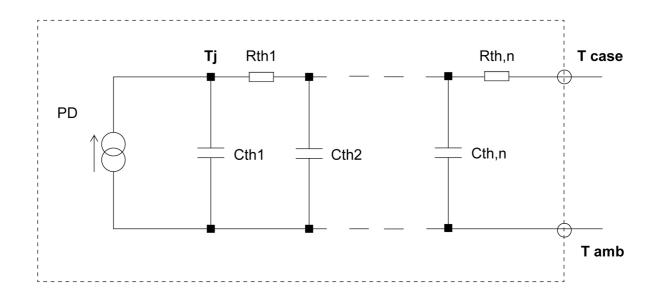


Fig.1 Power Dissipation Derating Curve

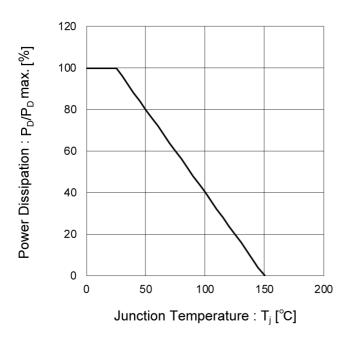


Fig.2 Drain Current Derating Curve

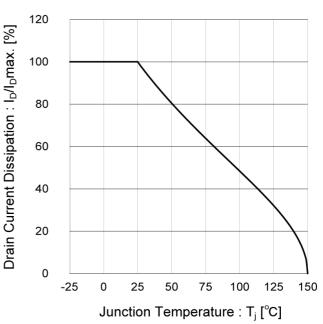


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

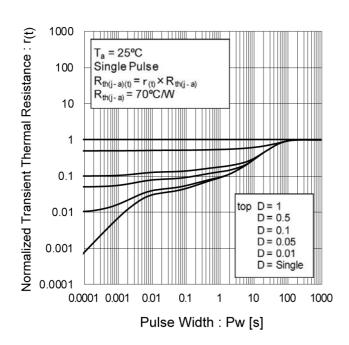
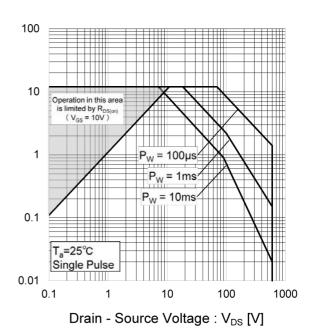


Fig.4 Maximum Safe Operating Area



Drain Current : I_D [A]

Fig.5 Avalanche Energy Derating Curve

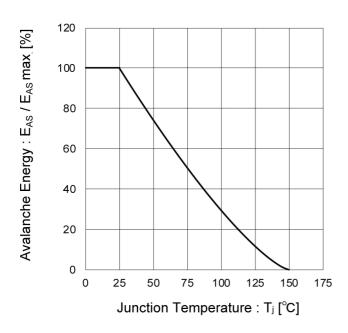


Fig.6 Normalized Breakdown Voltage vs. Junction Temperature

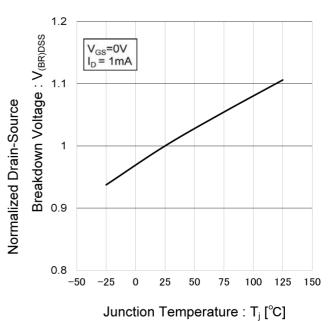


Fig.7 Typical Output Characteristics(I)

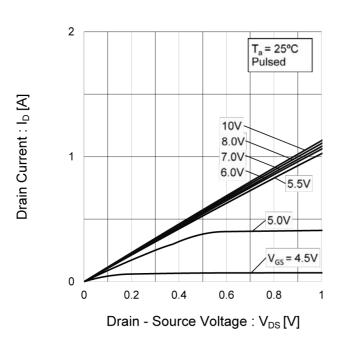
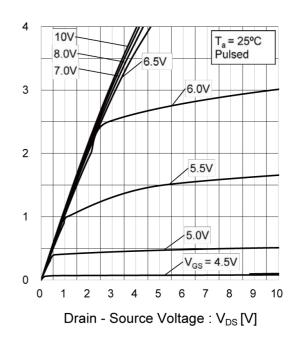


Fig.8 Typical Output Characteristics(II)



Drain Current : I_D [A]

Fig.9 Typical Transfer Characteristics

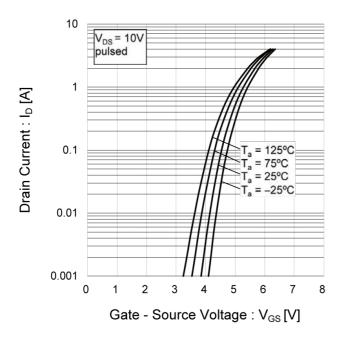


Fig.10Gate Threshold

Voltage vs. Junction Temperature

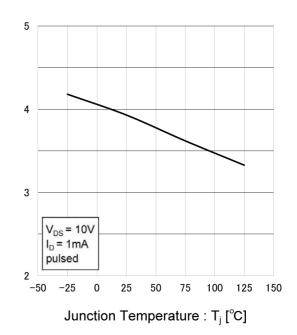


Fig.11 Static Drain - Source On - State Resistance vs. Drain Current

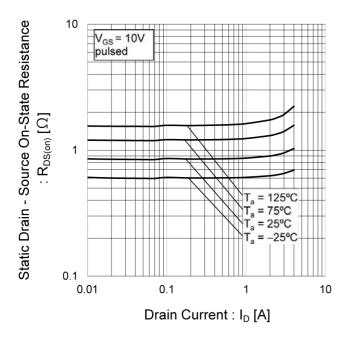
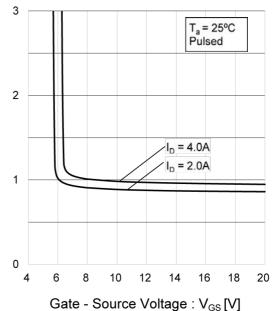


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



Static Drain - Source On-State Resistance

 $R_{\text{DS(on)}}\left[\Omega\right]$

Gate Threshold Voltage: V_{GS(th)} [V]

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

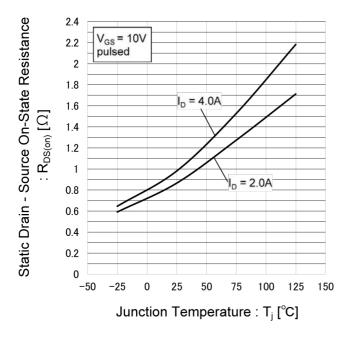


Fig.14 Typical Capacitance vs.

Drain - Source Voltage

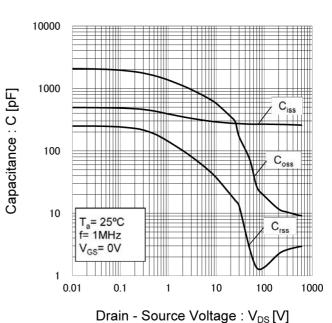


Fig.15 Switching Characteristics

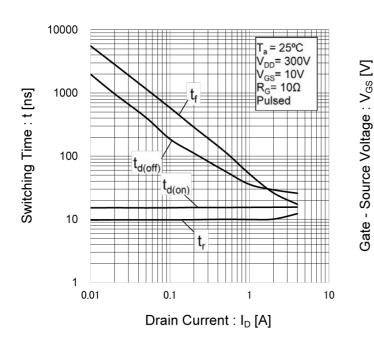
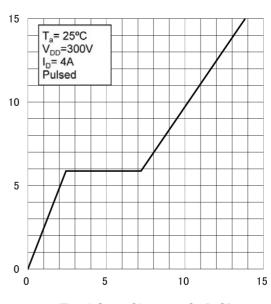
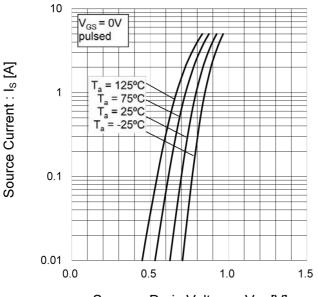


Fig.16 Typical Gate Charge



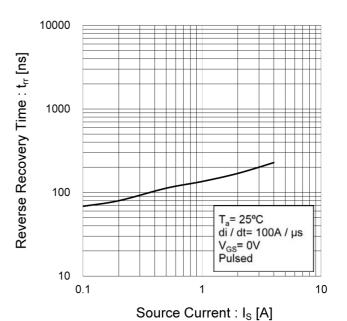
Total Gate Charge : Qg [nC]

Fig.17 Source Current vs. Source - Drain Voltage



Source - Drain Voltage : V_{SD} [V]

Fig.18 Reverse Recovery Time vs. Source Current



Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

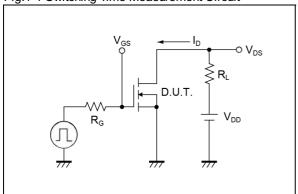


Fig.2-1 Gate Charge Measurement Circuit

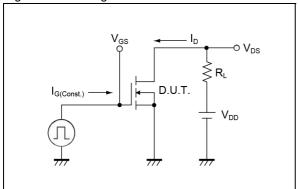


Fig.3-1 Avalanche Measurement Circuit

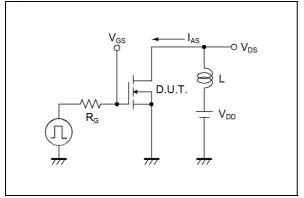


Fig.4-1 trr Measurement Circuit

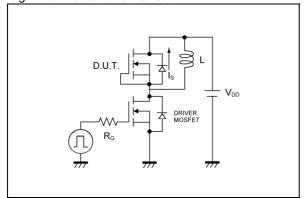


Fig.1-2 Switching Waveforms

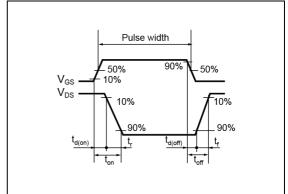


Fig.2-2 Gate Charge Waveform

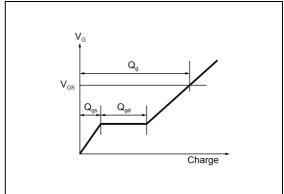


Fig.3-2 Avalanche Waveform

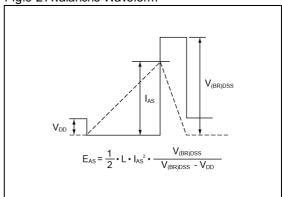
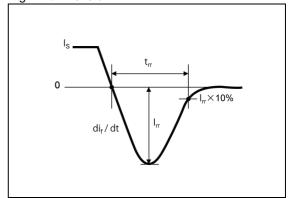
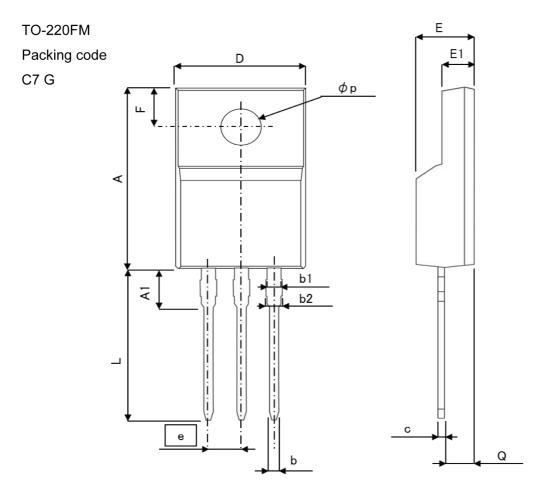


Fig.4-2 trr Waveform



Dimensions

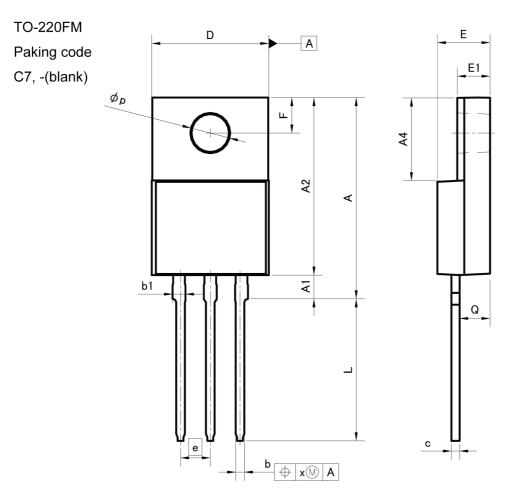


DIM	MILIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	15.67	16.27	0.617	0.641
A1	3.03	3.43	0.119	0.135
b	0.70	0.95	0.028	0.037
b1	1.00	1.40	0.039	0.055
b2	1.10	1.50	0.043	0.059
С	0.45	0.65	0.018	0.026
D	9.90	10.30	0.390	0.406
E	4.60	5.00	0.181	0.197
E1	2.44	2.74	0.096	0.108
е	2.	54	0.1	00
F	3.10	3.50	0.122	0.138
L	12.6	13.6	0.946	0.535
р	2.98	3.38	0.117	0.133
Q	2.25	3.25	0.089	0.128

Dimension in mm/inches



Dimensions



DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	16.60	17.60	0.654	0.693
A1	1.80	2.20	0.071	0.087
A2	14.80	15.40	0.583	0.606
A4	6.80	7.20	0.268	0.283
b	0.70	0.90	0.028	0.035
b1	1.10	1.50	0.043	0.059
С	0.70	0.85	0.028	0.033
D	9.90	10.30	0.390	0.406
E	4.40	4.80	0.173	0.189
е	2.	54	0.1	00
E1	2.70	3.00	0.106	0.118
F	2.80	3.20	0.110	0.126
L	11.50	12.50	0.453	0.492
р	3.00	3.40	0.118	0.134
Q	2.10	3.10	0.083	0.122
х	_	0.38	a—3	0.015

Dimension in mm/inches



Notice

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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSII	CLASS II b	CLASSIII
CLASSIV		CLASSⅢ	

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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
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 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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Notice-PGA-E Rev.004

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